Dual 1-of-4 Decoder/ Demultiplexer

The SN74LS156 is a high speed Dual 1-of-4 Decoder/Demultiplexer. This device has two decoders with common 2-bit Address inputs and separate gated Enable inputs. Decoder "a" has an Enable gate with one active HIGH and one active LOW input. Decoder "b" has two active LOW Enable inputs. If the Enable functions are satisfied, one output of each decoder will be LOW as selected by the address inputs. The LS156 has open collector outputs for wired-OR (DOT-AND) decoding and function generator applications.

The LS156 is fabricated with the Schottky barrier diode process for high speed and are completely compatible with all ON Semiconductor TTL families.

- Schottky Process for High Speed
- Multifunction Capability
- Common Address Inputs
- True or Complement Data Demultiplexing
- Input Clamp Diodes Limit High Speed Termination Effects
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
Vcc	Supply Voltage	4.75	5.0	5.25	V
TA	Operating Ambient Temperature Range	0	25	70	°C
Voн	Output Voltage – High			5.5	V
lOL	Output Current – Low			8.0	mA



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LS156-OPEN-COLLECTOR LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 648

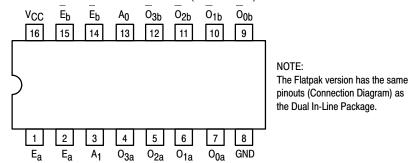


SOIC D SUFFIX CASE 751B

ORDERING INFORMATION

Device	Package	Shipping
SN74LS156N	16 Pin DIP	2000 Units/Box
SN74LS156D	SOIC-16	38 Units/Rail
SN74LS156DR2	SOIC-16	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

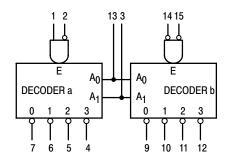


		LOADING	(Note a)
PIN NAMES		HIGH	LOW
$\underline{A}_0, \underline{A}_1$	Address Inputs	0.5 U.L.	0.25 U.L.
E _a , E _b	Enable (Active LOW) Inputs	0.5 U.L.	0.25 U.L.
<u>E</u> a _	Enable (Active HIGH) Input	0.5 U.L.	0.25 U.L.
0n - 0a	Active LOW Outputs	10 U.L.	5 U.L.

NOTES:

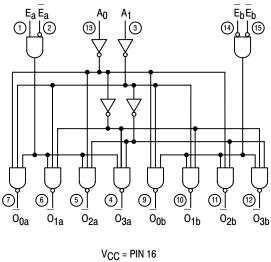
a) 1 TTL Unit Load (U.L.) = 40 μA HIGH/1.6 mA LOW.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

LOGIC DIAGRAM



V_{CC} = PIN 16 GND = PIN 8

= PIN NUMBERS

FUNCTIONAL DESCRIPTION

The LS156 is a Dual 1-of-4 Decoder/Demultiplexer with common Address inputs and separate gated Enable inputs. When enabled, each decoder section accepts the binary weighted Address inputs (A₀, A₁) and provides four mutually exclusive active LOW outputs (O₀–O₃). If the Enable requirements of each decoder are not met, all outputs of that decoder are HIGH.

Each decoder section has a 2-input enable gate. The enable gate for Decoder "a" requires one active HIGH input and one active LOW input $(E_a \bullet E_a)$. In demultiplexing applications, Decoder "a" can accept either true or complemented data by using the E_a or E_a inputs respectively. The enable gate for Decoder "b" requires two active LOW inputs $(E_b \bullet E_b)$. The LS155 or LS156 can be used as a 1-of-8 Decoder/Demultiplexer by tying E_a to E_b and relabeling the common connection as (A_2) . The other E_b and E_a are connected together to form the common enable.

The LS156 can be used to generate all four minterms of two variables. These four minterms are useful in some applications replacing multiple gate functions as shown in Fig. a. The LS156 has the further advantage of being able to AND the minterm functions by tying outputs together. Any number of terms can be wired-AND as shown below.

$$f = (E_+ + A_0 + A_1) \cdot (E + \overline{A_0} + A_1) \cdot (E + A_0 + \overline{A_1}) \cdot (E + \overline{A_0} + \overline{A_1}) \cdot (E + \overline{A_$$

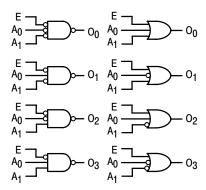


Figure a

TRUTH TABLE

ADDF	RESS	ENAB	LE "a"		OUTPL	JT "a"		ENAB	LE "b"		OUTP	UT "b"	
A ₀	A ₁	Ea	Ea	00	01	02	03	E _b	E _b	00	01	02	03
Х	Х	L	Х	Н	Н	Н	Н	Н	Х	Н	Н	Н	Н
Х	Χ	Х	Н	Н	Н	Н	Н	Х	Н	Н	Н	Н	Н
L	L	Н	L	L	Н	Н	Н	L	L	L	Н	Н	Н
Н	L	Н	L	Н	L	Н	Н	L	L	Н	L	Н	Н
L	Н	Н	L	Н	Н	L	Н	L	L	Н	Н	L	Н
Н	Н	Н	L	Н	Н	Н	L	L	L	Н	Н	Н	L

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
VIH	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
VIL	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
VIK	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA		
IOH	Output HIGH Current			100	μΑ	V _{CC} = MIN, V _{OH} = MAX		
	Outrot I OW Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	V _{CC} = V _{CC} MIN,	
VOL	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
l	lancet HOLL Command			20	μΑ	V _{CC} = MAX, V _{IN} = 2.7 V		
I'IH	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
IIL	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
Icc	Power Supply Current			10	mA	V _{CC} = MAX		

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits					
Symbol	Parameter	Min Typ Max Unit Test Conditi		Conditions			
^t PLH ^t PHL	Propagati <u>o</u> n De <u>lay</u> Address, E _a or E _b to Output		25 34	40 51	ns	Figure 1	
^t PLH ^t PHL	Propagation Delay Address to Output		31 34	46 51	ns	Figure 2	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 15 \text{ pF}$ $R_{L} = 2.0 \text{ k}\Omega$
tPLH tPHL	Propagation Delay E _a to Output		32 32	48 48	ns	Figure 1	_ ·

AC WAVEFORMS

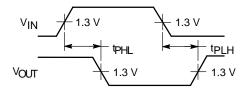


Figure 1.

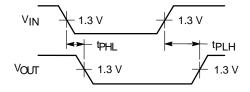
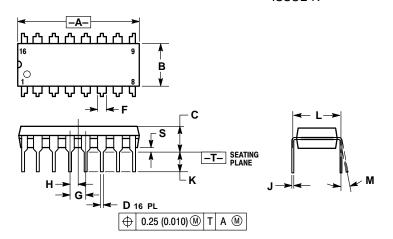


Figure 2.

PACKAGE DIMENSIONS

N SUFFIX PLASTIC PACKAGE CASE 648-08 ISSUE R

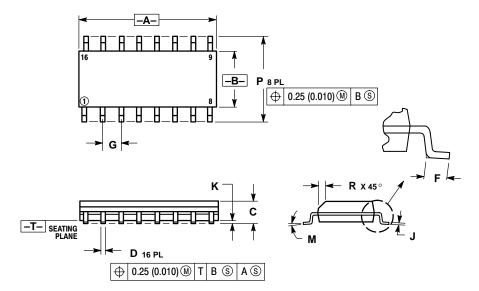


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10°	0°	10 °	
S	0.020	0.040	0.51	1.01	

PACKAGE DIMENSIONS

D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 **ISSUE J**



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES			
DIM	MIN	MIN MAX		MAX		
Α	9.80	10.00	0.386	0.393		
В	3.80	4.00	0.150	0.157		
С	1.35	1.75	0.054	0.068		
D	0.35	0.49	0.014	0.019		
F	0.40	1.25	0.016	0.049		
G	1.27	BSC	0.050 BSC			
J	0.19	0.25	0.008	0.009		
K	0.10	0.25	0.004	0.009		
M	0°	7°	0°	7°		
P	5.80	6.20	0.229	0.244		
R	0.25	0.50	0.010	0.019		

Notes

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